

Rectifier Diode

Type W3697VC160 to W3697VC280

Old Type No.: SW02-20CXC16C

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	1600-2800	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	1700-2900	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=55^{\circ}C$, (note 2)	3697	A
$I_{F(AV)M}$	Maximum average forward current. $T_{sink}=100^{\circ}C$, (note 2)	2530	A
$I_{F(AV)M}$	Maximum average forward current. $T_{sink}=100^{\circ}C$, (note 3)	1520	A
$I_{F(RMS)M}$	Nominal RMS forward current, $T_{sink}=25^{\circ}C$, (note 2)	6840	A
$I_{F(d.c.)}$	D.C. forward current, $T_{sink}=25^{\circ}C$, (note 4)	5840	A
I_{FSM}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}=0.6V_{RRM}$, (note 5)	40	kA
I_{FSM2}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	45	kA
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}=0.6V_{RRM}$, (note 5)	8.0×10^6	A^2s
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	10.1×10^6	A^2s
$T_{j\ op}$	Operating temperature range	-55 to +160	$^{\circ}C$
T_{stg}	Storage temperature range	-55 to +180	$^{\circ}C$

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}C$ is applicable for T_j below $25^{\circ}C$.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, $160^{\circ}C$ T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{FM}	Maximum peak forward voltage	-	-	1.54	I _{TM} =6800A	V
V _{FM}	Maximum peak forward voltage	-	-	1.95	I _{TM} =11100A	V
V _{T0}	Threshold voltage	-	-	0.86		V
r _T	Slope resistance	-	-	0.1		mΩ
I _{R_{RRM}}	Peak reverse current	-	-	60	Rated V _{RRM}	mA
I _{R_{RRM}}	Peak reverse current	-	-	60	Rated V _{RRM} , T _j =25°C	mA
R _{thJK}	Thermal resistance, junction to heatsink	-	-	0.016	Double side cooled	K/W
		-	-	0.032	Single side cooled	K/W
F	Mounting force	27	-	34		kN
W _t	Weight	-	1000	-		g

Notes:-

- 1) Unless otherwise indicated T
- _j
- =160°C.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{DRM} V_{DSM} V_{RRM} V	V_{RSM} V	V_D V_R DC V
16	1600	1700	1050
18	1800	1900	1150
20	2000	2100	1250
22	2200	2300	1350
24	2400	2500	1450
26	2600	2700	1550
28	2800	2900	1600

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_0 + \sqrt{V_0^2 + 4 \cdot ff^2 \cdot r_s \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_s} \quad \text{and:} \quad W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j \max} - T_{Hs}$$

Where V₀=0.86V, r_s=0.1mΩ,

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave Double Side Cooled	0.01643	0.01576	0.01526	0.01487	0.01429	0.01371	0.01328
Square wave Single Side Cooled	0.03426	0.03399	0.03373	0.03348	0.03300	0.03234	0.03174
Sine wave Double Side Cooled	0.01583	0.01507	0.01463	0.01429	0.01351		
Sine wave Single Side Cooled	0.03405	0.03371	0.03344	0.03318	0.03246		

Form Factors							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave	3.464	2.449	2	1.732	1.414	1.149	1
Sine wave	3.98	2.778	2.22	1.879	1.57		

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F , on page 6 is represented in two ways;

- (i) the well established V_0 and r_s tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for hot characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	160°C Coefficients
A	0.2946829
B	0.100011
C	1.106436×10^{-4}
D	-4.781509×10^{-3}

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{-\frac{t}{\tau_p}} \right)$$

Where $p = 1$ to n , n is the number of terms in the series and:

- t = Duration of heating pulse in seconds.
- r_t = Thermal resistance at time t.
- r_p = Amplitude of p_{th} term.
- τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Single Side Cooled		
Term	1	2
r_p	0.54145	2.62145
τ_p	0.07599	0.03111

D.C. Double Side Cooled				
Term	1	2	3	4
r_p	0.06465	0.04241	0.02065	5.09×10^{-3}
τ_p	0.29708	0.10877	0.04414	2.95×10^{-3}

Curves

Figure 1 - Forward characteristics of Limit device

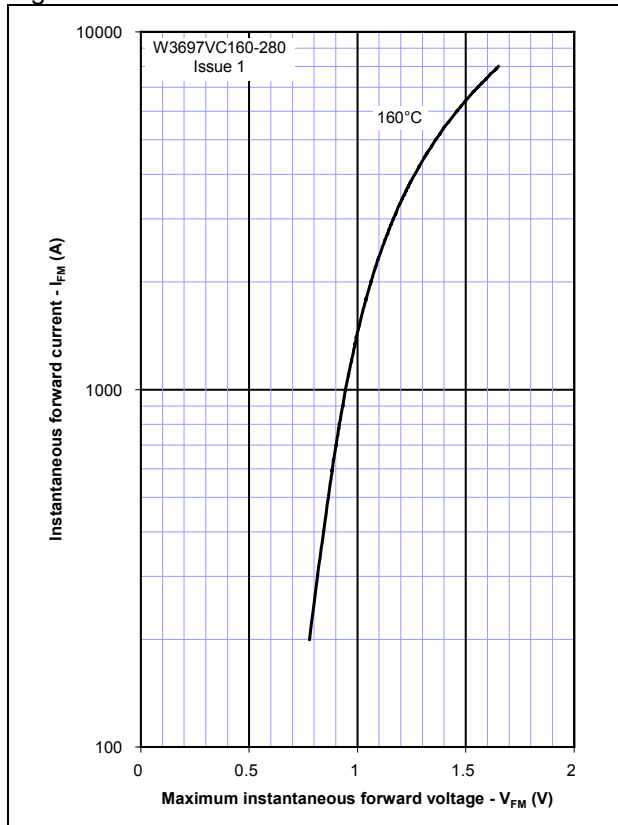


Figure 2 - Transient thermal impedance

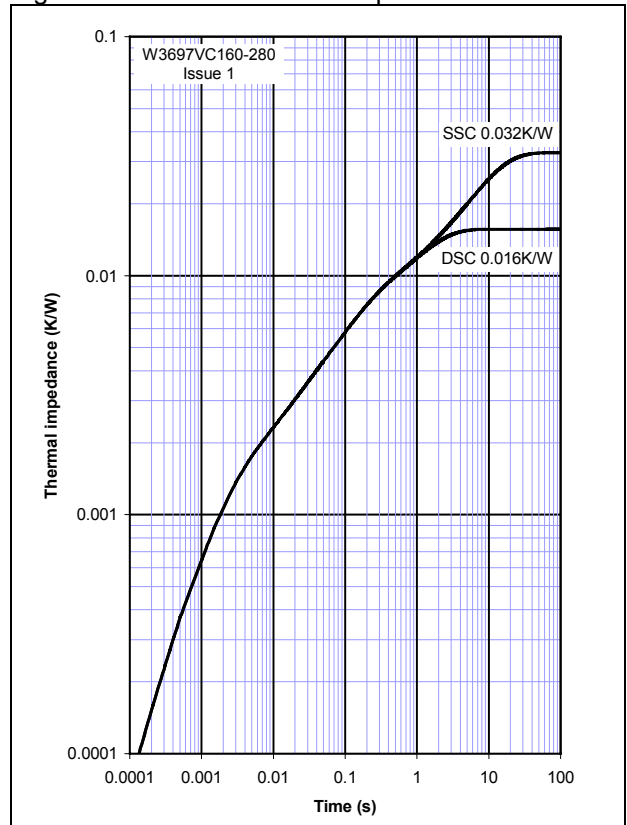


Figure 3 - Maximum surge Rating

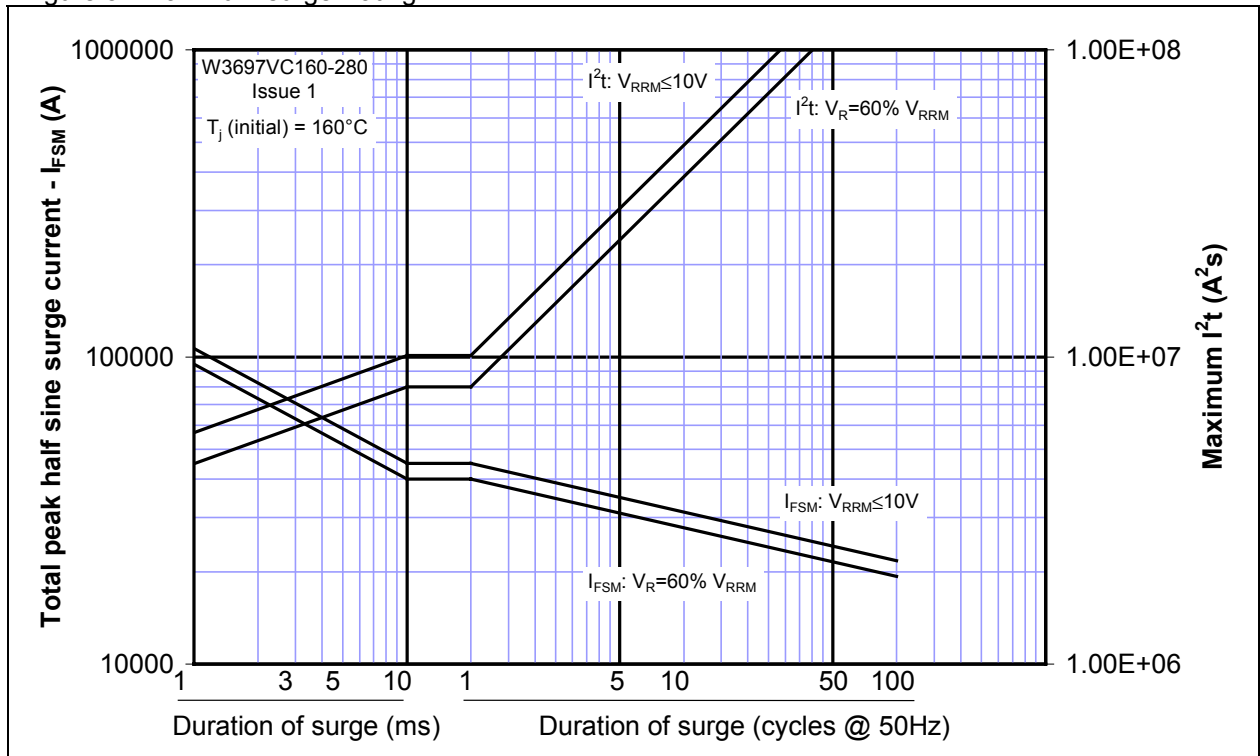


Figure 4 – Forward current vs. Power dissipation – Double Side Cooled

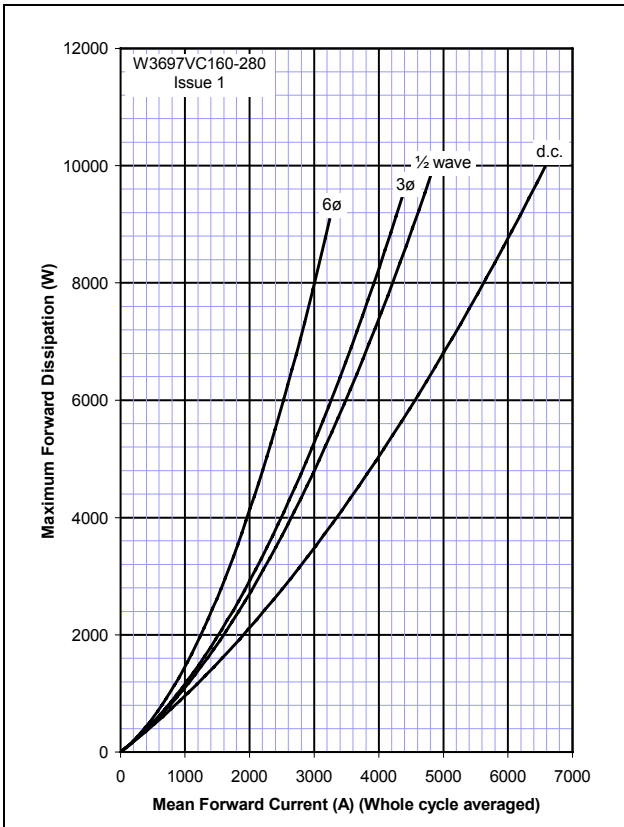


Figure 5 – Forward current vs. Heatsink temperature - Double Side Cooled

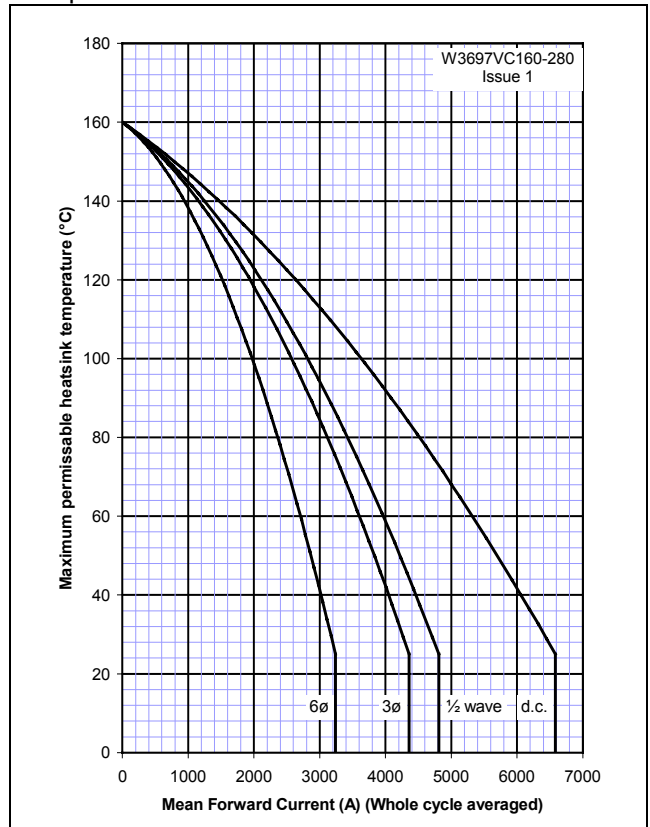


Figure 6 – Forward current vs. Power dissipation – Single Side Cooled

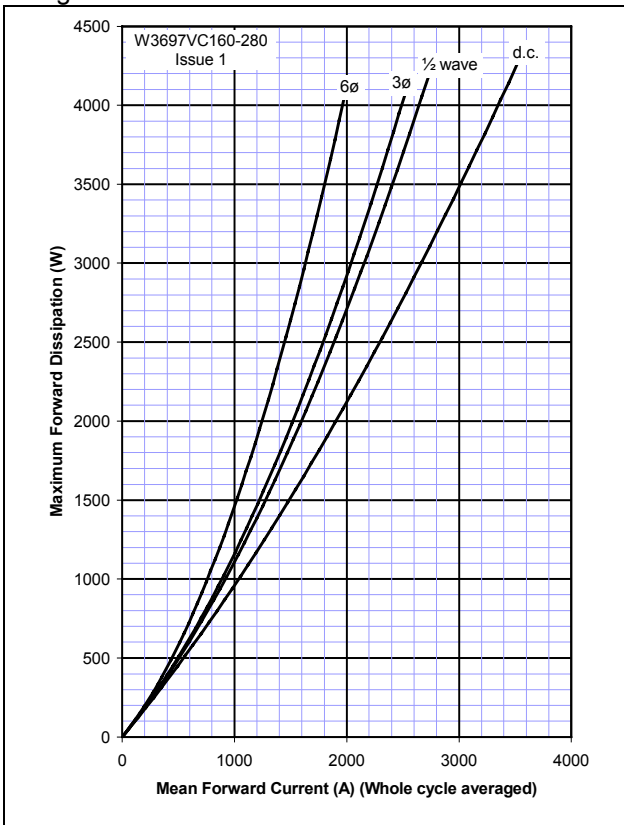
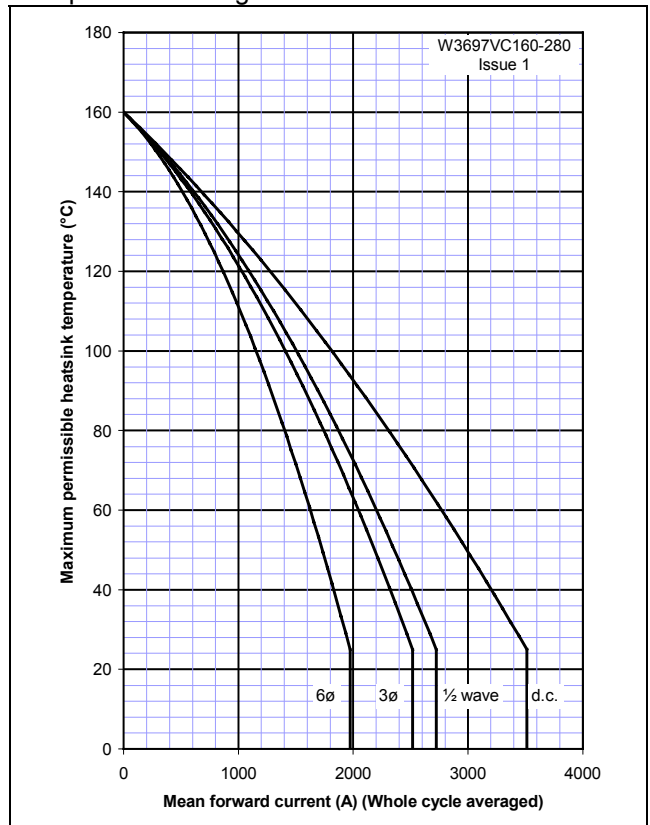
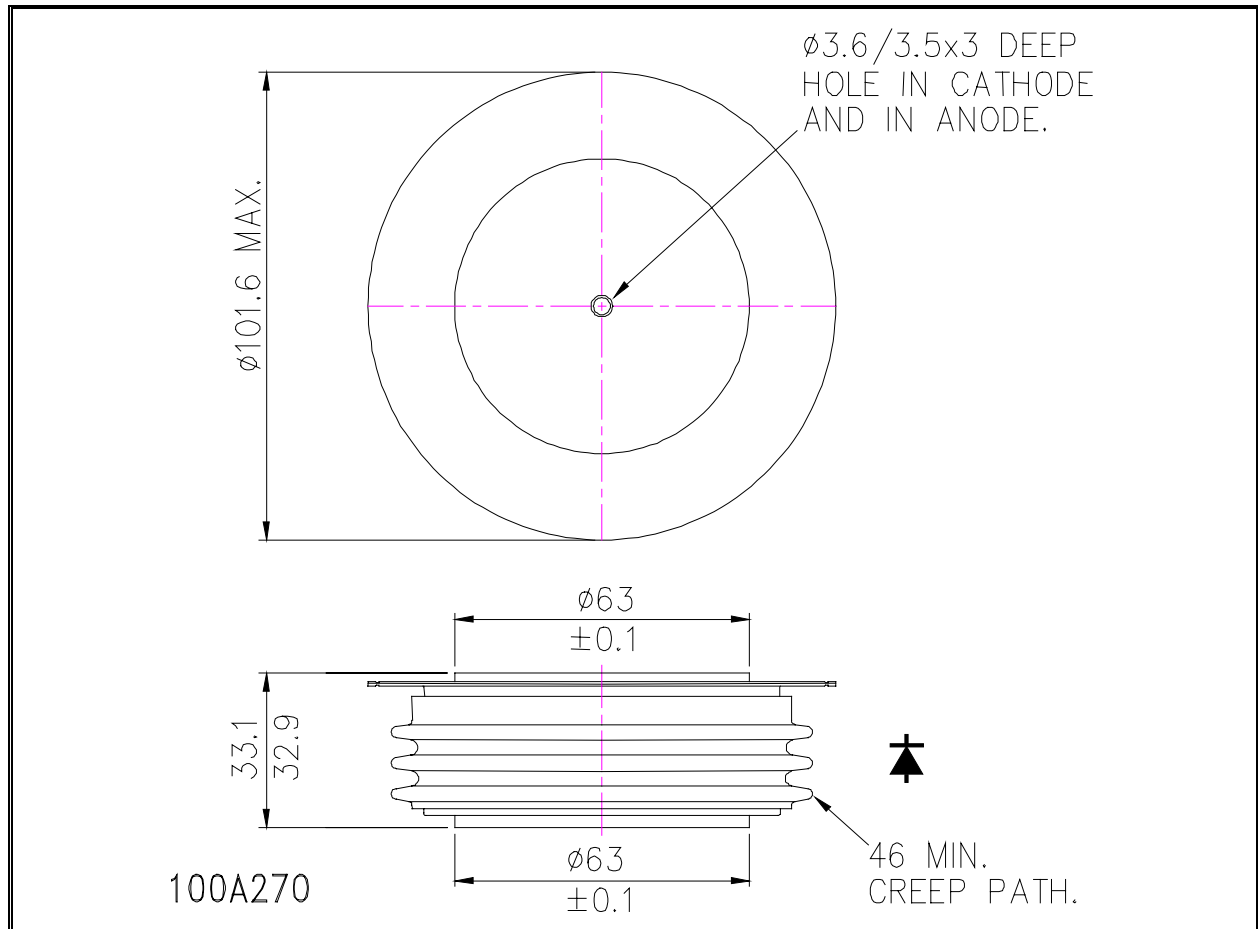


Figure 7 – Forward current vs. Heatsink temperature – Single Side Cooled



Outline Drawing & Ordering Information



ORDERING INFORMATION			
(Please quote 10 digit code as below)			
W3697	VC	◆◆	0
Fixed Type Code	Fixed outline code	Voltage code $V_{DRM/100}$ 16-28	Fixed turn-off time code

Order code: W3697VC180- 1800V V_{RRM} , 33.1mm clamp height capsule.

IXYS Semiconductor GmbH
 Edisonstraße 15
 D-68623 Lampertheim
 Tel: +49 6206 503-0
 Fax: +49 6206 503-627
 E-mail: marcom@ixys.de

WESTCODE
 An IXYS Company

Westcode Semiconductors Ltd
 Langley Park Way, Langley Park,
 Chippenham, Wiltshire, SN15 1GE.
 Tel: +44 (0)1249 444524
 Fax: +44 (0)1249 659448
 E-mail: WSL.sales@westcode.com

IXYS Corporation
 3540 Bassett Street
 Santa Clara CA 95054 USA
 Tel: +1 (408) 982 0700
 Fax: +1 (408) 496 0670
 E-mail: sales@ixys.net

www.westcode.com

www.ixys.com

Westcode Semiconductors Inc
 3270 Cherry Avenue
 Long Beach CA 90807 USA
 Tel: +1 (562) 595 6971
 Fax: +1 (562) 595 8182
 E-mail: WSI.sales@westcode.com

The information contained herein is confidential and is protected by Copyright. The information may not be used or disclosed except with the written permission of and in the manner permitted by the proprietors Westcode Semiconductors Ltd.

© Westcode Semiconductors Ltd.

In the interest of product improvement, Westcode reserves the right to change specifications at any time without prior notice.

Devices with a suffix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.